Carbon Nanotube and Graphene Device Physics

Explaining the properties and performance of practical nanotube devices and related applications, this is the first introductory textbook on the subject. All the fundamental concepts are introduced, so that readers without an advanced scientific background can follow all the major ideas and results. Additional topics covered include nanotube transistors and interconnects, and the basic physics of graphene. Problem sets at the end of every chapter allow readers to test their knowledge of the material covered and gain a greater understanding of the analytical skillsets developed in the text. This is an ideal textbook for senior undergraduate and graduate students taking courses in semiconductor device physics and nanoelectronics. It is also a perfect self-study guide for professional device engineers and researchers.

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“An excellent and timely volume on the physics and applications of carbon nanotubes. A must read for students and researchers in this hot field.”

Yuan Taur, UCSD

“This is the textbook that I have been aspiring to see for a long time. With excellent timing, the authors provide one that covers device physics of carbon nanotubes in a coherent, systematic way. The content is perfectly designed and formulated such that both students with little knowledge and researchers with hands-on experience in the field would find it extremely valuable. I would highly recommend this book to anyone who is interested in ‘post-silicon’ electronics.”

Bin Yu, State University of New York, Albany

“I strongly recommend this text book to students, engineers and researchers who wish to build up their knowledge on carbon nanotube fundamentals and applications. They will extend their learning from materials technology and solid state physics to their applications in the fields of nanoelectronics and micro- nanosystems. The readers, interested by graphene and carbon nanotubes based devices, have the possibility to train themselves on the hottest topics and challenges which will pave the future of nanotechnology.”

Simon Deleonibus, IEEE Fellow, CEA-LETI Chief Scientist and Research Director, MINATEC, Grenoble, France.

“This book is an excellent overview of carbon-based electronics, and in particular it provides the reader with an up-to-date and crisp description of the physical and electrical phenomena of carbon nanotubes, as well as a perspective on new applications enabled by this nanotechnology. Both experts and students will enjoy reading this book, as it brings up to focus the important details of carbon solid-state physics to understand the ground rules of carbon transistors and the related nanoelectronic circuits. Moreover, from a global point of view, carbon electronics is a key nanotechnology supporting the continuous development of the information age in computing, sensing and networking.”

Giovanni De Micheli, EPFL

“Excellent book covering all aspects of carbon nanotube devices from basic quantum physics in solids over material and device physics to applications including interconnects, field effect transistors and sensors. First complete book in an exciting new nanoelectronics field with great potential, intended for undergraduate and graduate students, researchers in the field and professional engineers, enabling them to get an insight in the field or to broaden their competence.”

Cor Claeys, IMEC, Leuven, Belgium
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## Contents

1 Overview of carbon nanotubes  
1.1 Introduction 1  
1.2 An abbreviated zigzag history of CNTs 3  
1.3 Synthesis of CNTs 13  
1.4 Characterization techniques 16  
1.5 What about non-CNTs? 17

2 Electrons in solids: a basic introduction  
2.1 Introduction 19  
2.2 Quantum mechanics of electrons in solids 20  
2.3 An electron in empty space 21  
2.4 An electron in a finite empty solid 23  
2.5 An electron in a periodic solid: Kronig–Penney model 26  
2.6 Important insights from the Kronig–Penney model 29  
2.7 Basic crystal structure of solids 32  
2.8 The Bravais lattice 33  
2.9 The reciprocal lattice 38  
2.10 Summary 42  
2.11 Problem set 42

3 Graphene  
3.1 Introduction 47  
3.2 The direct lattice 50  
3.3 The reciprocal lattice 51  
3.4 Electronic band structure 52  
3.5 Tight-binding energy dispersion 55  
3.6 Linear energy dispersion and carrier density 63
Contents

3.7 Graphene nanoribbons 67
3.8 Summary 70
3.9 Problem set 70

4 Carbon nanotubes 73
4.1 Introduction 73
4.2 Chirality: a concept to describe nanotubes 74
4.3 The CNTs lattice 76
4.4 CNTs Brillouin zone 81
4.5 General observations from the Brillouin zone 86
4.6 Tight-binding dispersion of chiral nanotubes 88
4.7 Band structure of armchair nanotubes 90
4.8 Band structure of zigzag nanotubes and the derivation of the bandgap 93
4.9 Limitations of the tight-binding formalism 95
4.10 Summary 97
4.11 Problem set 98

5 Carbon nanotube equilibrium properties 102
5.1 Introduction 102
5.2 Free-electron density of states in one dimension 103
5.3 Density of states of zigzag nanotubes 105
5.4 Density of states of armchair nanotubes 111
5.5 Density of states of chiral nanotubes and universal density of states for semiconducting CNTs 113
5.6 Group velocity 116
5.7 Effective mass 117
5.8 Carrier density 119
5.9 Summary 124
5.10 Problem set 125

6 Ideal quantum electrical properties 128
6.1 Introduction 128
6.2 Quantum conductance 129
6.3 Quantum conductance of multi-wall CNTs 134
6.4 Quantum capacitance 139
6.5 Quantum capacitance of graphene 142
6.6 Quantum capacitance of metallic CNTs 144
6.7 Quantum capacitance of semiconducting CNTs 145
Contents

6.8 Experimental validation of the quantum capacitance for CNTs 147
6.9 Kinetic inductance of metallic CNTs 148
6.10 From Planck to quantum conductance: an energy-based derivation of conductance 151
6.11 Summary 153
6.12 Problem set 154

7 Carbon nanotube interconnects 157
7.1 Introduction 157
7.2 Electron scattering and lattice vibrations 158
7.3 Electron mean free path 163
7.4 Single-wall CNT low-field resistance model 168
7.5 Single-wall CNT high-field resistance model and current density 171
7.6 Multi-wall CNT resistance model 174
7.7 Transmission line interconnect model 176
7.8 Lossless CNT transmission line model 182
7.9 Lossy CNT transmission line model 183
7.10 Performance comparison of CNTs and copper interconnects 184
7.11 Summary 186
7.12 Problem set 188

8 Carbon nanotube field-effect transistors 191
8.1 Introduction 191
8.2 Survey of CNFET device geometries 192
8.3 Surface potential 195
8.4 Ballistic theory of ohmic-contact CNFETs 200
8.5 Ballistic theory of CNFETs including drain optical phonon scattering 206
8.6 Ballistic CNFET performance parameters 209
8.7 Quantum CNFETs 212
8.8 Schottky-barrier ballistic CNFETs 213
8.9 Unipolar CNFETs 223
8.10 Paradigm difference between conventional 2D MOSFETs and ballistic 1D FETs 225
8.11 Summary 227
8.12 Problem set 228
# Contents

9 Applications of carbon nanotubes 233

9.1 Introduction 233

9.2 Chemical sensors and biosensors 234

9.3 Probe tips for scanning probe microscopy 236

9.4 Nano-electromechanical systems (NEMS) 237

9.5 Field emission of electrons 238

9.6 Integrated electronics on flexible substrates 240

9.7 Hydrogen storage 242

9.8 Composites 244

9.9 References 245

Index 249
Preface

Carbon nanotubes have come a long way since their modern rediscovery in 1991. This time period has afforded a great many scholars across the globe to conduct a vast amount of research investigating their fundamental properties and ensuing applications. Finally, after two decades, the knowledge and understanding obtained, once only accessible to select scholars, is now sufficiently widespread and accepted that the time is ripe for a textbook on this matter. This textbook develops the basic solid-state and device physics of carbon nanotubes and to a lesser extent graphene. The lesser coverage of graphene is simply due to its relative infancy, with a good deal of the device physics still in its formative stage.

The technical discourse starts with the solid-state physics of graphene, subsequently warping into the solid-state physics of nanotubes, which serves as the foundation of the device physics of metallic and semiconducting nanotubes. An elementary and limited introduction to the device physics of graphene nanoribbons and graphene are also developed. This textbook is suitable for senior undergraduates and graduate students with prior exposure to semiconductor devices. Students with a background in solid-state physics will find this book dovetails with their physics background and extends their knowledge into a new material that can potentially have an enormous impact in society. Scholars in the fields of materials, devices, and circuits and researchers exploring ideas and applications of nanoscience and nanotechnology will also find the book appealing as a reference or to learn something new about an old soul (carbon). Research into potential applications of carbon nanotubes has been progressing at a rapid pace. We have refrained from cataloging the continual progress in applications because it is simply impossible to keep up with the developments. Instead, we focus on the fundamental physics and principles so the reader can easily utilize them for the application at hand. Scattered throughout the book are many references that offer further coverage on the technical matters for the interested reader. However, owing to the restricted space there are many outstanding references that are not cited in this book. The avid reader will find much educational pleasure in perusing the technical literature from time to time, as this is a rapidly advancing field of research.
Our “carbon journey” started when one of us was at the IBM T.J. Watson Research Center in Yorktown Heights, New York. Richard Martel (now at Université de Montréal) and Phaedon Avouris were generous with sharing their knowledge; and the management – John Warlaumont and Tom Theis – fostered a nurturing intellectual environment within the confines of an industrial research laboratory. The kernel of this book started from sections of a graduate-level course at Stanford University, first taught in the Fall of 2005. We thank the students who asked the pertinent questions and offered suggestions for improvements. We also want to take this opportunity to thank all our reviewers that devoted their valuable time in improving the final product. We incorporated most of your feedback and apologize that the limited time prevented some feedback from coming through. Thanks to Tayo Akinwande (MIT), Phaedon Avouris (IBM), Zhihong Chen (IBM, Purdue), Azad Naeemi (Georgia Tech), Eric Pop (UIUC), Emmanuel Tutuc (University of Texas), Yin Yuen (Stanford), and Jerry Zhang (Stanford). Your efforts are sincerely appreciated. Now that the textbook is published, we continue to welcome any and all feedback. Errors and omissions of all sorts will no doubt be brought to light despite our best intentions to produce an error-free textbook. As such, we anticipate errata will be made available at Cambridge University Press website and updated as the case warrants. An online resource for instructors is also available at the website: www.cambridge.org/wong.

It has been a great pleasure writing this textbook on the device physics of carbon materials. For us, this book was a labor of love, and the adventure involved in developing the content along a unifying theme was a great enriching experience and sufficient reward in and of itself. We hope that all readers will similarly find great enrichment and understanding as they explore the pages of this book. Finally, we would like to thank our families – the Akinwande clan, Cecilia Mui, Amelia Wong, and Emily Wong – for their support and understanding.

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